

LU	1/2	
3 I	Hours / 100 Marks Seat No.	
	 Instructions: (1) All questions are compulsory. (2) Answer each next main question on a new page. (3) Illustrate your answers with neat sketches wherever necessary. (4) Assume suitable data, if necessary. 	
	Ma	rks
1.	Attempt any ten:	20
	a) Define:	
	i) Active components ii) Passive components.	
	b) Draw the symbol of	
	i) N-channel JFET ii) P-channel JFET.	
	c) Draw V-I characteristics of PN diode.	
	d) List any two types of couplings used in amplifier.	
	e) Define Barrier potential. Give its values for Si and Ge diode.	
	f) Give two advantages of ICS.	
	g) Give necessity of filters in DC power supply.	
	h) Define transconductance of JFET.	
	i) Draw the symbols of	
	i) Varacter diode ii) LDR.	
	j) Give classification of ICs.	
	k) Give two applications of Light Emitting Diode.	
	l) Enlist two examples of non linear resistors.	
2.	Attempt any four:	16
	a) State any four applications of electronics in day to day life.	
	b) Draw symbol of Zener Diode. Draw and explain its V-I characteristics.	
	c) Draw neat sketch of NPN Transistor. Describe its working.	
	d) Derive relation between α and β .	
	e) Give construction and working of Tunnel diode.	
	f) Define Oscillator. Give Bark Hausen Criteria for sustained oscillations.	

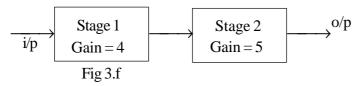
Marks

3. Attempt any four:

16

- a) Give construction and working of LDR.
- b) Draw the neat sketch of common emitter amplifier.
- c) Give construction and working of Field Effect Transistor.
- d) Give two applications of
 - a) Varacter diode

- b) Tunnel diode.
- e) Given $I_R = 110 \,\mu$ A, $I_C = 2 \,\text{mA}$. For a transistor find α and β .
- f) Describe the need of multistage amplifier.



Find out overall gain.

4. Attempt any four:

16

- a) Give four applications of Schottky diode.
- b) Draw the neat sketch of center tap full wave rectifier. Draw input and output waveforms.
- c) Compare BJT and FET (any four points).
- d) Draw and explain working of CLC filter.
- e) Draw the neat sketch of two stage transformer coupled amplifier.
- f) Draw and explain construction and working of crystal oscillator circuit.

5. Attempt any four:

16

- a) Describe process of formation of Depletion Layer.
- b) Compare Half wave, full wave center tap and full wave bridge type rectifier (four points).
- c) State and explain the operating principle of P-N junction diode under forward bias condition.
- d) Give construction of Bistable multivibrator using transistor.
- e) List two advantages and disadvantages of R-C coupled amplifier.
- f) Describe working of Zener diode as voltage regulator.

6. Attempt any four:

16

- a) Describe static resistance and dynamic resistance of PM junction diode.
- b) Define Rectifier. State its need. Define the terms:
 - i) Ripple Factor

- ii) Efficiency.
- c) Define "Biasing of Transistor." Explain in brief voltage divider biasing.
- d) Draw DC load line of transistor. Explain working of transistor as a switch.
- e) Draw and explain Drain characteristics of JFET.
- f) Draw neat sketch of half wave rectifier. List its two disadvantages. Draw input output waveforms.